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Magnetoconductance of the quantum spin Hall state

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We study the edge magnetoconductance of a quantum spin Hall insulator in the presence of quenched nonmagnetic disorder. For a finite magnetic field B and disorder strength W on the order of the bulk gap E_g, the system is a 1D Anderson insulator with inverse localization length linear in $|B|$ for small B, in qualitative agreement with the cusp-like features observed in recent magnetotransport measurements on HgTe quantum wells. We propose a dimensional crossover scenario as a function of W, in which for weak disorder $W < E_g$ the edge liquid is analog to a disordered spinless 1D quantum wire, while for strong disorder $W > E_g$, the disorder causes frequent virtual transitions to the 2D bulk, where the originally 1D edge electrons can undergo 2D diffusive motion and 2D antilocalization.

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A great deal of interest has been generated recently by the theoretical prediction [1] and experimental observation [2, 3, 4] of the quantum spin Hall (QSH) insulator state [5, 6, 7]. The QSH state is a novel topological state of quantum matter which does not break time-reversal symmetry (TRS), but has a bulk insulating gap and gapless edge states with a distinct helical liquid property [8]. The gaplessness of the edge states is protected against weak TRS preserving perturbations by Kramers degeneracy [8, 9]. As a result, the QSH state exhibits robust dissipationless edge transport [2, 3, 4] in the presence of nonmagnetic disorder.

However, in the presence of an external magnetic field which explicitly breaks TRS, the gaplessness of the edge states is not protected. This can be simply understood by considering the generic form of the effective 1D Hamiltonian H for the QSH edge [10] to first order in the magnetic field $\mathbf{B}$, $H = H_0 + H_1(\mathbf{B})$, where $H_0 = \hbar v k\sigma_3$ is the Hamiltonian of the unperturbed edge, and $H_1(\mathbf{B}) = \sum_{a=1,2,3}(\mathbf{t}_a \cdot \mathbf{B})\sigma_a$ is the perturbation due to the field. k is a 1D wave vector along the edge, v is the edge state velocity, $\sigma_{1,2,3}$ are the three Pauli spin matrices, and $\mathbf{t}_{1,2,3}$ are model-dependent coefficient vectors [10]. If $\mathbf{B}$ points along a special direction in space $\mathbf{t}^* \equiv \mathbf{t}_1 \times \mathbf{t}_2$, then $H_1(\mathbf{B}) \propto \sigma_3$ commutes with H_0, the wave vector k is simply shifted, and the edge remains gapless, unless mesoscopic quantum confinement effects become important [11]. If $\mathbf{B} \nparallel \mathbf{t}^*$, then $[H_0, H_1(\mathbf{B})] \neq 0$ and a gap $E_{\text{gap}} \propto |B|$ opens in the edge state dispersion.

Experimentally [2, 12], one observes that the conductance $G(B)$ of a QSH device exhibits a sharp cusp-like peak at $B = 0$, and G decreases for increasing $|B|$. Although the explanation of a thermally activated behavior $G(B) \propto e^{-E_{\text{gap}}(|B|)/k_BT}$ with T the temperature can account qualitatively for the observed cusp, it does so only if the chemical potential μ lies inside the edge gap which, according to theoretical estimates [7], is rather small ($E_{\text{gap}} \sim 1$ meV). Experimentally, a sharp peak is observed [12] throughout the bulk gap ($E_g \sim 40$ meV). Furthermore, this explanation ignores the effects of disorder. In the absence of TRS, the QSH edge liquid is topologically equivalent to a spinless 1D quantum wire, and is thus expected to be strongly affected by disorder due to Anderson localization. Although the effect of disorder on transport in the QSH state has been the subject of several recent studies [8, 9, 13, 14, 15, 16, 17], except for studies addressing the effect of magnetic impurities [8, 18] there have been no theoretical investigations of the combined effect of disorder and TRS breaking on edge transport in the QSH state.

In this work, we study numerically the edge magnetoconductance G of a QSH insulator in the presence of quenched nonmagnetic disorder. Our main findings are: (1) For a finite magnetic field B and disorder strength W on the order of the bulk energy gap E_g, the system behaves as a 1D Anderson insulator, with inverse localization length $\xi^{-1} \propto |B|$ for small B (Fig. 2a), for μ across the bulk gap (Fig. 1c). This agrees qualitatively with the cusp-like features reported in Ref. 2. (2) ξ^{-1} increases rapidly when $W > E_g$ (Fig. 2b), which suggests that bulk states play an important role in the backscattering of the edge states. (3) G is unaffected by an orbital magnetic field in the absence of inversion symmetry breaking terms (Fig. 3a). In the absence of such terms, $\mathbf{t}_1$ and $\mathbf{t}_2$ are entirely in the xy plane of the device [7], hence $\mathbf{t}^* \propto \hat{\mathbf{z}}$ is out-of-plane and a perpendicular field $\mathbf{B} \parallel \mathbf{t}^*$ cannot lead to backscattering, as discussed earlier. In the presence of inversion symmetry breaking terms, the effective edge Hamiltonian becomes $H' = \hbar v k\sigma'_3 + \sum_{a=1,2,3}(\mathbf{t}'_a \cdot \mathbf{B})\sigma'_a$, where σ'_3 has nonzero components along the 1 and 2 directions. Then $\mathbf{t}'^* = \mathbf{t}'_1 \times \mathbf{t}'_2$ is not along $\hat{\mathbf{z}}$ anymore, and a perpendicular field $\mathbf{B} = B\hat{\mathbf{z}}$ can lead to backscattering.

Model.—We start from a 4-band effective Hamiltonian introduced by Bernevig, Hughes and Zhang (BHZ) [1, 7] for the QSH state in HgTe quantum wells (QW),

$$\mathcal{H}_{\mathbf{k}} = \begin{pmatrix} H_{\mathbf{k}} & \Delta_{\mathbf{k}} \\ \Delta_{\mathbf{k}}^\dagger & H^*_{-\mathbf{k}} \end{pmatrix}, \Delta_{\mathbf{k}} = \begin{pmatrix} \Delta_e k_+ & -\Delta_z \\ \Delta_z & \Delta_h k_- \end{pmatrix}, \quad (1)$$

where $H_{\mathbf{k}}$ and its TRS conjugate $H^*_{-\mathbf{k}}$ are 2D Dirac-like Hamiltonians given in Eq. (6) of Ref. 7 and $\Delta_{\mathbf{k}}$ originates from the bulk inversion asymmetry (BIA) of the zincblende structure of HgTe/CdTe [19], with $\Delta_{e,h,z}$ some $\mathbf{k} \cdot \mathbf{p}$ parameters [20] and $k_\pm = k_x \pm ik_y$. An effective tight-binding

(TB) model on the square lattice can be derived from Eq. (1), $\mathcal{H} = \sum_i c_i^\dagger V c_i + \sum_i \left(c_i^\dagger T_{\hat{x}} c_{i+\hat{x}} + c_i^\dagger T_{\hat{y}} c_{i+\hat{y}} + \text{H.c.}\right)$, where the 4×4 matrices $V, T_{\hat{x}}, T_{\hat{y}}$ depend only on $\mathbf{k}\cdot\mathbf{p}$ parameters. In the presence of disorder and an external magnetic field, we perform the substitutions $V \to V + H_{Z\parallel} + H_{Z\perp} + W_i$ and $T_{\hat{x}} \to T_{\hat{x}} e^{\frac{2\pi i}{\phi_0}\int_i^{i+\hat{x}} d\boldsymbol{\ell}\cdot\mathbf{A}} = T_{\hat{x}} e^{-2\pi i n_z y/a}$, where W_i is a Gaussian random potential with standard deviation W mimicking quenched disorder, $\mathbf{A} = (-B_z y, 0)$ is the vector potential in the Landau gauge, $\phi_0 = h/e$ is the flux quantum, and $n_z = B_z a^2/\phi_0$ is the number of flux quanta per plaquette with a the lattice constant. We use $a = 30$ Å which is a good approximation to the continuum limit. The in-plane $H_{Z\parallel}(B_x, B_y)$ and out-of-plane $H_{Z\perp}(B_z)$ Zeeman terms are given in Eq. (38) of Ref. 7. The parameters used in this work correspond to a HgTe QW thickness of $d = 80$ Å.

We calculate numerically the $T = 0$ disordered-averaged two-terminal conductance G and conductance fluctuations δG of a finite QSH strip (Fig. 1a) using the standard TB Green function approach [21]. For a strip of width L_y comparable to the edge state penetration depth λ, interedge tunneling [22] backscatters the edge states even at $B = 0$ and the system is analog to a topologically trivial quasi-1D quantum wire. To ensure that we are studying effects intrinsic to the topologically nontrivial QSH helical edge liquid, we first need to suppress interedge tunneling. The naive way to achieve this is to use a very large L_y; however, this can be computationally rather costly. We use a geometry (Fig. 1a) which allows us to effectively circumvent this problem while keeping L_y reasonable. By adding a local Dirac mass term [7] $\delta M < 0$ on the first horizontal chain of our TB model (Fig. 1a, red dots), the penetration depth λ_2 at the top edge becomes much smaller than that at the bottom edge $\lambda_1 \gg \lambda_2$. We then add disorder only to the last L_{dis}/a chains of the central region with $L_{\text{dis}} \gg \lambda_1$ and $L_y - L_{\text{dis}} \gg \lambda_2$. The resulting top edge states are very narrow, contribute an uninteresting background quantized conductance independent of B and W, and are essentially decoupled from the bottom edge states (whose magnetoconductance we wish to study) that are effectively propagating in a semi-infinite disordered medium. Finally, in order to address the length dependence of the magnetoconductance we define the inverse localization length ξ^{-1} as [23]

$$\xi^{-1}(\mu) = -\lim_{N_x\to\infty}\frac{1}{N_x}\left\langle \ln \sum_{y\alpha,y'\alpha'}\left|\mathcal{G}^{\alpha\alpha'}_{1y,N_x y'}(\mu)\right|^2\right\rangle_{\text{dis}},$$

where $\mathcal{G}(\mu)$ is the retarded Green function of the device at the chemical potential μ, $\alpha, \alpha' = 1, \ldots, 4$ are band indices, $y, y' = 1, \ldots, N_y$ are transverse (y direction) site indices, and $\langle\cdots\rangle_{\text{dis}}$ denotes disorder averaging. In practice, the limit $N_x \to \infty$ is essentially reached for $N_x \sim 2000$, and $N_{\text{dis}} \sim 100$ disorder configurations are enough to achieve good convergence for $G, \delta G, \xi^{-1}$.

Numerical results.—For μ inside the bulk gap, we expect edge transport to dominate the physics. The typical behavior of the magnetoconductance $G(B)$ for $\mathbf{B} = B\hat{\mathbf{z}}$ and disorder strength W larger than the bulk gap $E_g \simeq 40$ meV is shown in Fig. 1b. The cusp-like feature at $B = 0$ agrees qualitatively with the results of Ref. 2. $G(B)$ is independent of L_y, which suggests that transport is indeed carried by the edge states. $G(B = 0)$ is quantized to $G_0 = 2e^2/h$ independent of W up to $W = 71$ meV with extremely small conductance fluctuations $\delta G(B = 0)/G_0 \sim 10^{-5}$, which confirms that interedge tunneling is negligible even for strong disorder. Furthermore, G tends to $G_0/2$ for large $|B| \sim 1$ T, which indicates that the disordered bottom edge is completely localized for large W and $|B|$, and only the unperturbed top edge conducts. For $W < E_g$, G is approximately quadratic in B (not shown), and $|G(B) - G_0|/G_0 \ll 1$ even for large $|B| \sim 1$ T. For $B \neq 0$, we observe that the amplitude of the fluctuations δG does not decrease upon increasing N_{dis}, and is roughly independent of W with $\delta G/G_0 \sim \mathcal{O}(10^{-1})$ for large enough disorder $W \gtrsim E_g$. Since in the absence of TRS the QSH system is a trivial insulator and the edge becomes analogous to an ordinary spinless 1D quantum wire with no topological protection, we conclude that δG corresponds to the well-known universal conductance fluctuations [21].

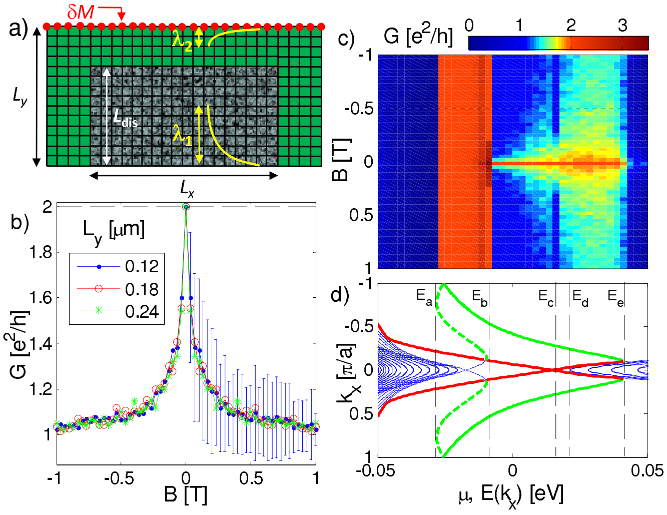

FIG. 1: Magnetoconductance G of a QSH edge: a) TB model with asymmetric edge states $\lambda_2 \ll \lambda_1$ to study a single disordered edge; b) dependence of G on sample width L_y for disorder strength $W = 55$ meV larger than the bulk gap, length $L_x = 2.4\,\mu$m, fixed clean width $L_y - L_{\text{dis}} = 0.03\,\mu$m, and local mass term $\delta M = -70$ meV, with error bars (plotted for $L_y = 0.12\,\mu$m and $B > 0$ only) corresponding to conductance fluctuations δG; c) dependence of G on chemical potential μ; d) quasi-1D spectrum of the device illustrated in a) for zero W, B, showing bulk states (blue), top edge states (green) and bottom edge states (red).

The dependence of $G(B)$ on μ is plotted in Fig. 1c. We consider $W = 55$ meV slightly larger than E_g (Fig. 1d). This is not unreasonable as the bulk mobility μ^* of the HgTe QW in Ref. 2 is estimated as $\mu^* \simeq 10^5$ cm^2/(V·s), which corresponds to a momentum relaxation time $\tau = \mu^* m^*/e \simeq 0.57$ ps. The bulk carriers at the bottom of the conduction subband

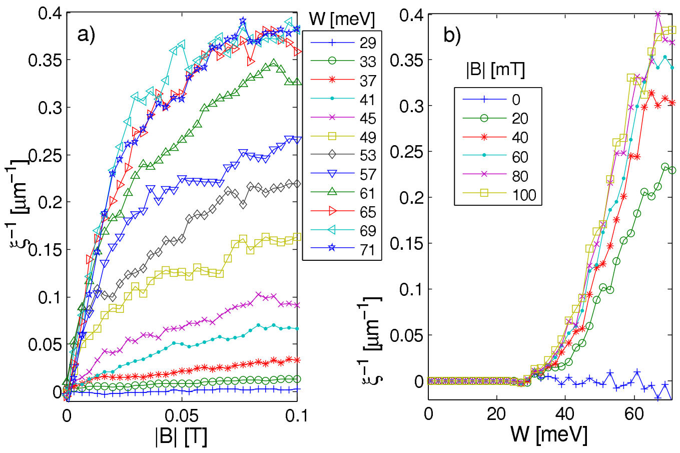

FIG. 2: Inverse localization length ξ^{-1} as a function of a) magnetic field $B = B_z$ and b) disorder strength W for sample width $L_y = 0.12\,\mu$m.

have an effective mass $m^* \simeq 0.01 m_e$ where m_e is the bare electron mass. τ is given by $\hbar/\tau \simeq 2\pi\nu(Wa)^2$, with ν the bulk continuum density of states at the Fermi energy given by $\nu \simeq m^*/\pi\hbar^2$. This yields $W \simeq 22$ meV. However, this estimate considers only bulk disorder and we expect edge roughness to yield a higher effective W on the edge. Furthermore, this estimate is perturbative in W and neglects interband effects which are expected to occur for $W \sim E_g$. For the chosen value of W we observe that the bulk states (Fig. 1d, blue lines) are strongly localized with $G \ll G_0$ for $\mu < E_a$ and $\mu > E_e$ in the bulk bands, while the cusp-like feature at $B = 0$ with $G(B = 0) = G_0$ remains prominent for $E_b < \mu < E_d$ in the bulk gap and even at the bottom of the conduction band $E_d < \mu < E_e$ where the top edge states (Fig. 1d, red lines) coexist with the bulk states. The sudden dip in $G(B \neq 0)$ for $\mu \sim E_c \simeq 15$ meV corresponds to the opening of the small edge gap discussed earlier. Finally, $G \simeq G_0$ is almost independent of B for $E_a < \mu < E_b$, where the disordered bottom edge and bulk states are mostly localized while the clean top edge supports another channel (Fig. 1d, dashed green line), with a total top edge conductance of $G = G_0$.

The inverse localization length ξ^{-1} for $B = B_z$ is plotted in Fig. 2. For $W < E_g$, ξ^{-1} is very small and difficult to calculate accurately. For the values $L_x \leq 6\,\mu$m that we use, $G(B)$ is approximately quadratic in B for $W < E_g$. For $W > E_g$, ξ^{-1} is approximately linear in $|B|$ for small B (Fig. 2a). This is consistent with the observation that $\partial G/\partial B \propto -|B|$ for small B in Fig. 1, since we find $G(B) \simeq G(0)e^{-L_x/\xi(B)}$. For $|B| > 0$, ξ^{-1} increases rapidly for $W \gtrsim E_g$ (Fig. 2b). For $B = 0$, ξ^{-1} is again very small and difficult to calculate accurately, but apart from fluctuations resulting from finite numerical accuracy we essentially have $\xi^{-1}(B = 0) \simeq 0$ independent of W (Fig. 2b). This contrasts with the results of Ref. 13, 16 where deviations from $G = G_0$ at $B = 0$ occur for W larger than some critical value $W_c > E_g$. The reason for this difference is that in Ref. 13, 16, disorder-induced collapse of the bulk gap is accompanied by the edge states penetrating deeper into the bulk and eventually reaching the opposite edge, such that interedge tunneling takes place and causes backscattering. Here, due to our special geometry (Fig. 1a) the top edge state is unperturbed and always remains localized near the edge, out of reach of the bottom edge state, even as the latter penetrates deeper into the disordered bulk for increasing W.

The BIA term $\Delta_{\mathbf{k}}$ has an important effect on G for $B = B_z$ (Fig. 3a). For simplicity, we set $\Delta_e = \Delta_h = 0$ and consider only the effect of Δ_z. For $\Delta_z = 0$, the perturbation $\mathcal{H}' = e\mathbf{j} \cdot \mathbf{A}$ due to an orbital field, with e the electron charge and $\mathbf{j}$ the current operator, has no matrix element between the spin states of a counterpropagating Kramers pair on a given edge [7], and G is unaffected. For an in-plane field, $H_{Z\|}$ does have a nonzero matrix element between these states, and there is a nontrivial magnetoconductance even in the absence of BIA.

The dependence of $G(B)$ on the orientation of $\mathbf{B}$ is plotted in Fig. 3b. The g-factors [20] used in the Zeeman terms are such that the Zeeman energies for in-plane and out-of-plane fields are of the same order [7]. The in-plane vs out-of-plane anisotropy (Fig. 3b, x, y vs z) arises from the orbital effect of the out-of-plane field $B = B_z$, which is absent for an in-plane field. In our model, the in-plane anisotropy is very weak (somewhat visible on Fig. 3b for $|B| \sim 1$ T), and is due to the inequivalence between the transport x and confinement y directions. Finally, the $B = 0$ peak in G is more pronounced for a smaller mass term M [7] in the Dirac Hamiltonians $H_{\mathbf{k}}, H^*_{-\mathbf{k}}$ (Fig. 3c). Since $E_g \propto |M|$ approximately, a smaller $|M|$ results in a larger dimensionless disorder strength W/E_g, which is equivalent to an increase in W (see Fig. 2b).

Although the mechanism behind the observed negative magnetoconductance $\partial G/\partial B \propto -|B|$ (Fig. 1,2) for an orbital field $B = B_z$ cannot be unambiguously inferred from our numerical results, an inverse localization length linear in $|B|$ for small B and the requirement of 'strong' disorder $W \gtrsim E_g$ for its observation seem to indicate that the effect has a nonperturbative character. A treatment which is perturbative in W and B yields at most, to leading order, the result $\xi^{-1} \propto \ell^{-1} \propto W^2_{\text{eff}}(B) \propto B^2$, where ℓ is the mean free path [24] and $W_{\text{eff}}(B) \equiv W|B|/B_0$ is some effective disorder strength, with $B_0^{-1} \propto \Delta_z$ if only the effect of Δ_z is considered for simplicity. For 'weak' disorder $W < E_g$, the 1D edge states which enclose a negligible amount of flux are the only low-energy degrees of freedom, and the magnetic field only has a perturbative effect on them. Indeed, if we choose the gauge $\mathbf{A} = \big(B_z(L_y - y), 0\big)$, for sufficiently small B_z we have that $\mathbf{A}$ is small for $L_y - \lambda_1 \lesssim y < L_y$ with $\lambda_1 \ll L_y$ where the bottom edge state wavefunction has finite support (Fig. 1a), and the effect of an orbital field B_z on a single edge can be treated perturbatively. In this case, the amplitude $\propto W_{\text{eff}}(B)$ in perturbation theory for a leading order backscattering process on a single edge involves one power of Δ_z and one power of B_z to couple the spin states of the counterpropagating Kramers partners [7] (with no momentum

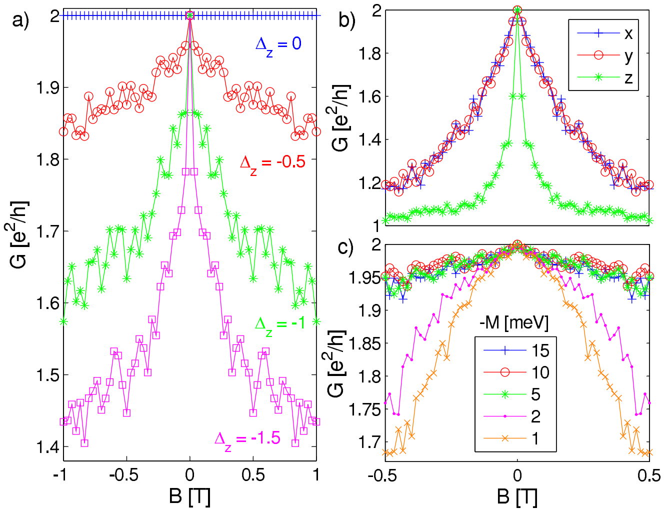

FIG. 3: Dependence of the magnetoconductance G on a) strength of the $\mathbf{k}$-independent BIA term Δ_z with $\Delta_e = \Delta_h = 0$; b) magnetic field orientation; c) Dirac mass term $M < 0$. Sample size is $(L_x \times L_y) = (2.4 \times 0.12)$ μm^2, disorder strength is $W = 55$ meV for a),b) and $W = 30$ meV for c).

transfer as our choice of gauge preserves translational symmetry in the x direction), and one power of W to provide the necessary momentum transfer for backscattering. Our observation that $G(B) - G_0 \propto -B^2$ for $W < E_g$ corroborates this physical picture. On the other hand, the cusp-like feature at $B = 0$ (Fig. 1b) occurs for 'strong' disorder $W \gtrsim E_g$, which seems to indicate that the bulk states play an important role. This leads us to a different physical picture. For $W \gtrsim E_g$, the edge electrons easily undergo virtual transitions to the bulk. In other words, the emergent low-energy excitations for $W \gtrsim E_g$ extend deeper into the bulk than the 'bare' edge electrons. The electrons spend a significant amount of time diffusing randomly in the bulk away from the edge, with their trajectories enclosing finite amounts of flux before returning to the edge, which endows the orbital field with a nonperturbative effect. In this way the conventional picture of 2D antilocalization (AL) [25] can apply, at least qualitatively, to a single disordered QSH edge. We are thus led to the interesting picture, peculiar to the QSH state, of a dimensional crossover between 1D AL [26, 27] in the weak disorder regime $W < E_g$ with the orbital field having a perturbative effect, to an effect analog to 2D AL in the strong disorder regime $W > E_g$ with the orbital field having a nonperturbative effect.

Conclusion.—We have shown that 'strong' disorder effects $W/E_g \sim 1$ in a QSH insulator in the presence of a magnetic field B and inversion symmetry breaking terms can give rise to a nonperturbative cusp-like feature in the two-terminal edge magnetoconductance and inverse localization length, i.e. $G(B) \simeq G(0)e^{-L_x/\xi(B)}$ with $\xi^{-1} \propto |B|$ for small B. A possible physical intepretation of our results consists of a dimensional crossover scenario where a weakly disordered, effectively spinless 1D edge liquid crosses over, for strong enough disorder, to a state where disorder enables frequent excursions of the edge electrons into the disordered flux-threaded 2D bulk, resulting in a behavior reminiscent of 2D AL.

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